

Effects of breathing and oblong mode phonons on transport properties in a single-electron transistor

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Erratum

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It has come to the attention of the authors that an error occurred in figure 3 of the above paper. An additional line appears below the $T = 4$ K line, which should not be there. The corrected figure is as follows:

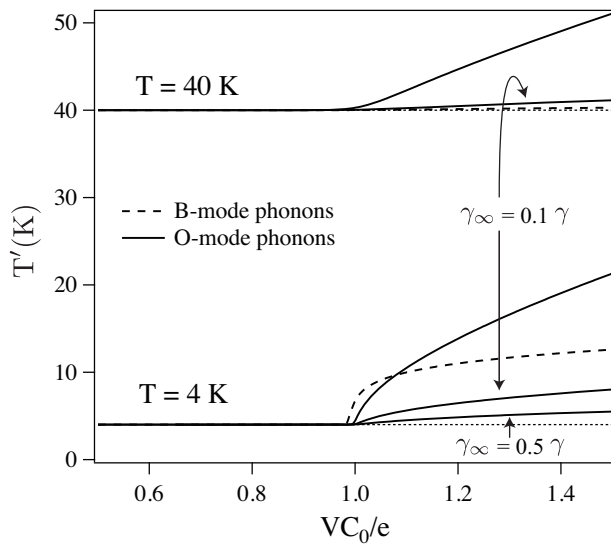


Figure 3. The temperature T' in the nanoparticle versus V at $T = 4$ K for $\gamma_\infty = 0.01\gamma$, 0.1γ and 0.5γ . The data lines of $\gamma_\infty = 0.1\gamma$ and 0.5γ are denoted by arrows. T is the temperature of the heat bath.